

GLF1110H, GLF11111H

Nano-Current Power I_QSmart[™] Load Switch

Product Specification

DESCRIPTION

The GLF1110H / GLF1111H is an ultra-efficiency, 2 A rated, Load Switch with integrated slew rate control. The best in class efficiency makes it an ideal choice for use in IoT, mobile, and wearable electronics.

The GLF1110H / GLF1111H features ultra-efficient I_QSmart^{TM} technology that supports the lowest quiescent current (I_Q) and shutdown current (I_{SD}) in the industry. Low I_Q and I_{SD} solutions help designers to reduce parasitic leakage current, improve system efficiency, and increase battery lifetime.

The integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF slew rate control specifically limits inrush currents during turn-on to minimize voltage droop.

The GLF1110H / GLF1111H supports an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduce operating cost.

FEATURES

Wide Input Range: 1.5 V to 5.5 V

6 V abs max

• R_{ON}: 54 m Ω Typ at 5.5 V_{IN}

• I_{OUT} Max: 2 A

Ultra-Low I_Q: 2 nA Typ at 5.5 V_{IN}
 Ultra-Low I_{SD}: 13 nA Typ at 5.5 V_{IN}

 \bullet Controlled Rise Time: 600 μs at 3.3 V_{IN}

• Internal EN Pull-Down Resistor

 Integrated Output Discharge Switch: GLF1111H

Wide Operating Temperature Range:

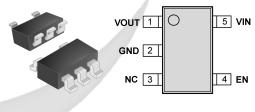
-40 °C ~ 105 °C

• HBM: 4 kV, CDM: 2 kV

APPLICATIONS

- Smart IoT Devices
- Portable Industrial Devices
- Low Power Subsystems

PACKAGE



SOT23-5L

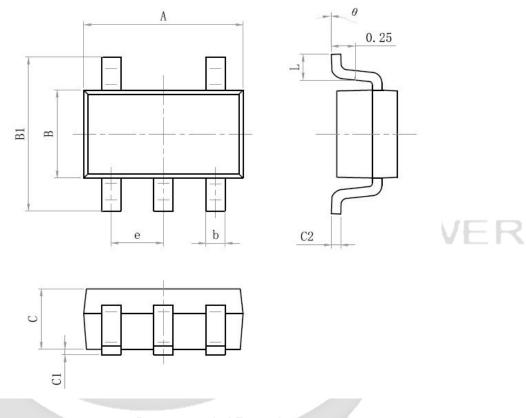
ALTERNATE DEVICE OPTIONS

Part Number	Top Mark	R _{ON} (Typ) at 5.5 V	Output Discharge	EN Activity		
GLF1110H-T1G7	DKH	54 mΩ	NA	High		
GLF1111H-T1G7	DLH	54 mΩ	85 Ω	High		

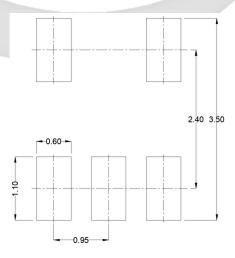


PACKAGE OUTLINE

Size Mark	Min(mm)	Min(mm) Max(mm)		Min(mm)	Max(mm)		
A	2.82	3.02	С	1.05	1.15		
е	0.9	95 (BSC)	C1	0.03	0.15		
b	0.28	0.45	C2	0.12	0.23		
В	1.50	1.70	L	0.35	0.55		
B1	2, 60	3, 00	θ	0°	8°		



Recommended Footprint

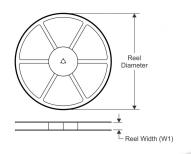


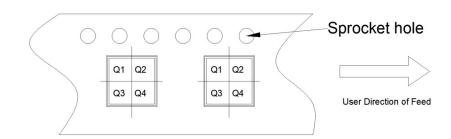
GLF1110H, GLF1111H Nano-Current Power I_QSmart™ Load Switch

TAPE AND REEL INFORMATION

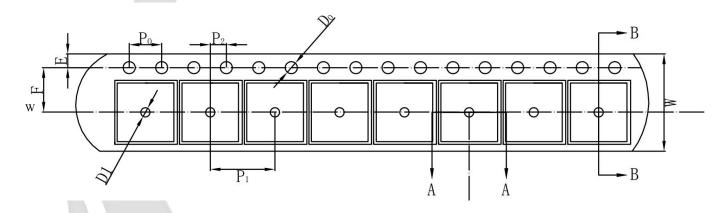
REEL DIMENSIONS

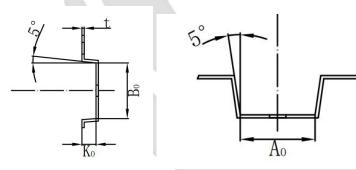
QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE





TAPE DIMENSIONS





Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	Α0	В0	K0	P1	w	Pin1
GLF1110H-T1G7	SOT23-5	5	3000	178	9	3.25	3.30	1.38	4	8	Q3
GLF1111H-T1G7	SOT23-5	5	3000	178	9	3.25	3.30	1.38	4	8	Q3

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape

Rev 0.0 Nov 2023

P1: Pitch between successive cavity centers